

# **UTC** UNISONIC TECHNOLOGIES CO., LTD

## 9N40

Preliminary

## 9A, 400V N-CHANNEL **POWER MOSFET**

#### DESCRIPTION

The UTC 9N40 is an N-channel mode power MOSFET using UTC's advanced technology to provide customers with planar stripe and DMOS technology. This technology specializes in allowing a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation mode.

The UTC 9N40 is universally applied in electronic lamp ballast based on half bridge topology and high efficient switched mode power supply.

#### **FEATURES**

- \* High switching speed
- \*  $R_{DS(ON)}$  < 0.75 $\Omega$  @  $V_{GS}$ =10V,  $I_{D}$ =4.5A
- \* 100% avalanche tested

#### **SYMBOL**



ORDERING INFORMATION

	Ordering Number		Deckogo	Pin Assignment			Deaking	
	Lead Free	Halogen Free	Package	1	2	3	Packing	
	9N40L-TA3-T	9N40G-TA3-T	TO-220	G	D	S	Tube	
	9N40L-TF1-T	9N40G-TF1-T	TO-220F1	G	D	S	Tube	
Note: Pin Assignment: G: Gate D: Drain S: Source								

9N40L-TA3-T	(1) T: Tube	
(2)Package Type	(2) TA3: TO-220, TF1: TO-220F1	
(3)Green Package	(3) L: Lead Free, G: Halogen Free and Lead Free	

#### MARKING





#### ■ ABSOLUTE MAXIMUM RATINGS (Tc=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V <sub>DSS</sub>	400	V
Gate-Source Voltage		V <sub>GSS</sub>	±30	V
Drain Current	Continuous (T <sub>C</sub> =25°C)	I <sub>D</sub>	9	А
	Pulsed (Note 2)	I <sub>DM</sub>	36	А
Avalanche Current (Note 2)		I <sub>AR</sub>	9	А
Avalanche Energy	Single Pulsed (Note 3)	E <sub>AS</sub>	427	mJ
Avalanche Energy	Repetitive (Note 2)	E <sub>AR</sub>	4.0	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	4.5	V/ns
Dower Dissinction	TO-220		113	W
Power Dissipation	TO-220F1		40	W
Derete chave 25°C	TO-220	PD	0.9	W/°C
Derate above 25°C	TO-220F1		0.32	W/°C
Junction Temperature		TJ	+150	°C
Storage Temperature		T <sub>STG</sub>	-55~+150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3. L = 10.5mH, I<sub>AS</sub> = 9A, V<sub>DD</sub> = 90V, R<sub>G</sub> = 25 $\Omega$ , Starting T<sub>J</sub> = 25°C.

4.  $I_{SD} \le 9A$ , di/dt  $\le 200A/\mu s$ ,  $V_{DD} \le BV_{DSS}$ , Starting  $T_J = 25^{\circ}C$ .

#### THERMAL DATA

PAF	PARAMETER		RATINGS	UNIT
Junction to Ambient		θ <sub>JA</sub>	62.5	°C/W
lunction to Coop	TO-220	0	1.1	°C/W
Junction to Case	TO-220F1	θ <sub>JC</sub>	3.125	°C/W



### ■ ELECTRICAL CHARACTERISTICS (T<sub>c</sub>=25°C, unless otherwise noted)

MIN TYP MAX	UNIT
400	V
1	μA
+100	nA
-100	nA
2.0 4.0	V
0.6 0.75	Ω
1340 1700	рF
490 520	pF
160 180	рF
34	nC
18	nC
16	nC
22	ns
60	ns
32	ns
140	ns
9	Α
36	Α
1.7	V
350	ns
2.6	μC
350	36

Notes: 1. Pulse Test: Pulse width  $\leq$  300µs, Duty cycle  $\leq$  2%.

2. Essentially independent of operating temperature.



## ■ TEST CIRCUITS AND WAVEFORMS

**Resistive Switching Test Circuit** 



Resistive Switching Waveforms



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